NEC

HIGH ISOLATION VOLTAGE SINGLE TRANSISTOR TYPE MULTI OPTOCOUPLER SERIES

PS2561-1, -2, -4
PS2561L-1, -2, -4

FEATURES

- **HIGH ISOLATION VOLTAGE (BV)**
  5000 $V_{r.m.s.}$: normal specification products
- **HIGH COLLECTOR TO EMITTER VOLTAGE**
  V_{CEO} = 80 V MIN
- **HIGH CURRENT TRANSFER RATIO**
  CTR: 200% TYP
- **HIGH SPEED SWITCHING**
  t_r = 3 µs, t_f = 5 µs TYP
- **ISOLATED CHANNELS PER EACH PACKAGE**

DESCRIPTION

PS2561-1, -2 and -4 and PS2561L-1, -2 and -4 are optically coupled isolators containing a GaAs light emitting diode and a NPN silicon phototransistor. PS2561-1, -2 and -4 are in a plastic DIP (Dual In-line Package) and PS2561L-1, -2 and -4 are in a lead bending type (Gull-wing) for surface mount.

APPLICATIONS

Interface circuit for various instrumentations, and control equipment.

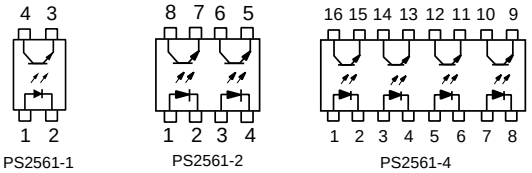
- **AC LINE / DIGITAL LOGIC**
- **DIGITAL LOGIC / DIGITAL LOGIC**
- **TWISTED PAIR LINE RECEIVER**
- **TELEPHONE / TELEGRAPH LINE RECEIVER**
- **HIGH FREQUENCY POWER SUPPLY FEEDBACK CONTROL**
- **RELAY CONTACT MONITOR**
- **POWER SUPPLY MONITOR**

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

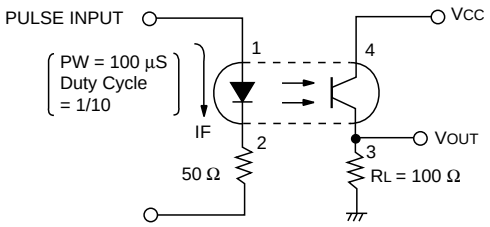
PART NUMBER				PS2561-1, -2, -4 PS2561L-1, -2, -4		
SYMBOLS		PARAMETERS	UNITS	MIN	TYP	MAX
Diode	V_F	Forward Voltage, I_F = 10 mA	V		1.17	1.4
	I_R	Reverse Current, V_R = 5 V	µA			5
	C	Junction Capacitance, V = 0, f = 1.0 MHz	pF		50	
Transistor	I_{CEO}	Collector to Emitter Dark Current, V_{CE} = 40 V, I_F = 0	nA			100
	BV_{CEO}	Collector to Emitter Breakdown Voltage, I_C = 1 mA, I_B = 0	V	40	60	
	BV_{ECO}	Emitter to Collector Breakdown Voltage, I_E = 100 µA, I_B = 0	V	7	9	
Coupled	CTR	Current Transfer Ratio[1], I_F = 5 mA, V_{CE} = 5 V	%	80	200	400
	$V_{CE(sat)}$	Collector Saturation Voltage, I_F = 10 mA, I_C = 2 mA	V			0.3
	R_{1-2}	Isolation Resistance, V_{in-out} = 1 k V	Ω	10^{11}		
	C_{1-2}	Isolation Capacitance, V = 0, f = 1.0 MHz	pF		0.5	
	t_r	Rise Time[2], V_{CC} = 10 V, I_C = 2 mA, R_L = 100 Ω	µs		3	
	t_f	Fall Time[2], V_{CC} = 10 V, I_C = 2 mA, R_L = 100 Ω	µs		5	

Note:

1. CTR Rank (PS2561-1, PS2561L-1 Only)
   L: 200 to 400 %
   M:80 to 240 %
   D: 100 to 300 %
   H: 80 to 160 %
   W: 130 to 260 %



2.Test Circuit for Switching Time



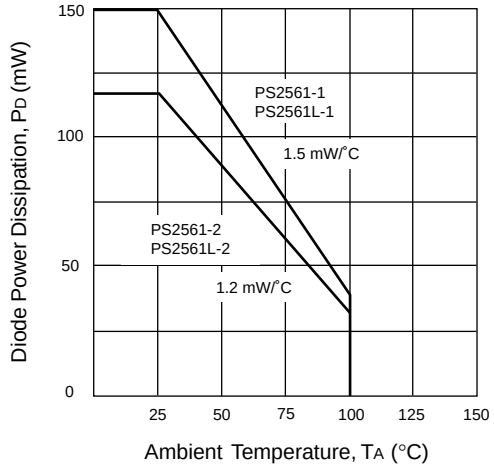
ABSOLUTE MAXIMUM RATINGS[1] (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS	
			PS2561 -1 PS2561L -1	PS2561 -2,-4 PS2561L -2,-4
Diode				
V_R	Reverse Voltage	V	6	6
I_F	Forward Current (DC)	mA	80	80
P_D	Power Dissipation	mW/Ch	150	120
$I_{F\ (PEAK)}$	Peak Forward Current (PW = 100 μs, Duty Cycle 1%)	A	1	1
Transistor				
V_{CEO}	Collector to Emitter Voltage	V	80	80
V_{ECO}	Emitter to Collector Voltage	V	7	7
I_C	Collector Current	mA	50	50
P_C	Power Dissipation	mW/Ch	150	120
Coupled				
BV	Isolation Voltage[2] normal speck	$V_{r.m.s.}$	5000	5000
BV	Isolation Voltage[2] VDE0884 speck	$V_{r.m.s.}$	3750	3750
P_T	Total Power Dissipation	mW/Ch	250	200
T_{STG}	Storage Temperature	°C	-55 to +150	-55 to +150
T_{OP}	Operating Temperature	°C	-55 to +100	-55 to +100
T_{SOL}	Lead Temperature (Soldering 10 s)	°C	260	260

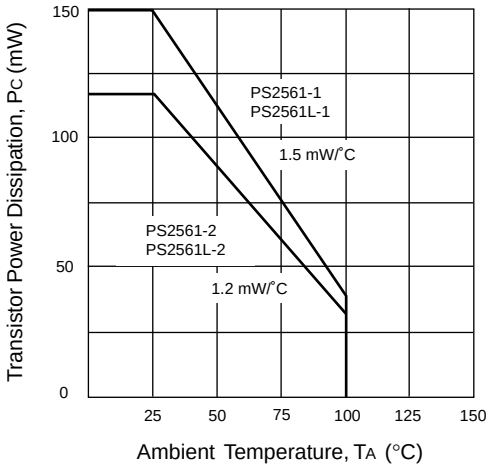
Notes:
1. Operation in excess of any one of these parameters may result in permanent damage.
2. AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and ouput.

TYPICAL PERFORMANCE CURVES (T_A = 25°)

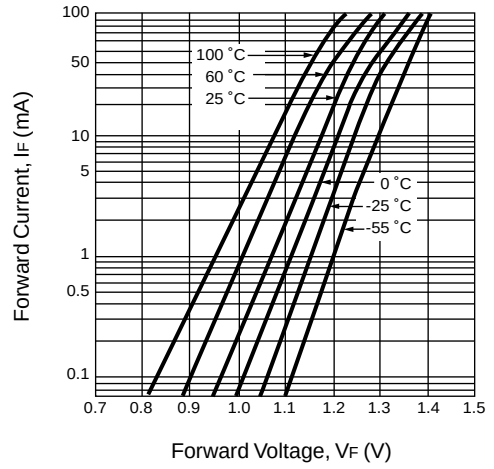
DIODE POWER DISSIPATION vs. AMBIENT TEMPERATURE



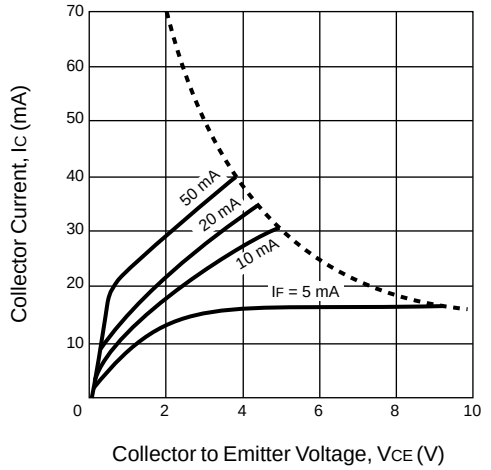
TRANSISTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



FORWARD CURRENT vs. FORWARD VOLTAGE

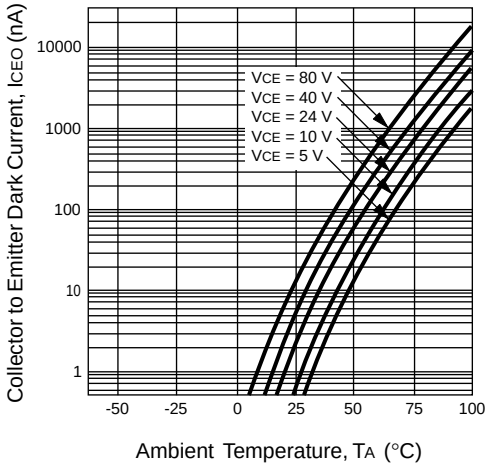


COLLECTOR CURRENT vs. COLLECTOR to EMITTER VOLTAGE

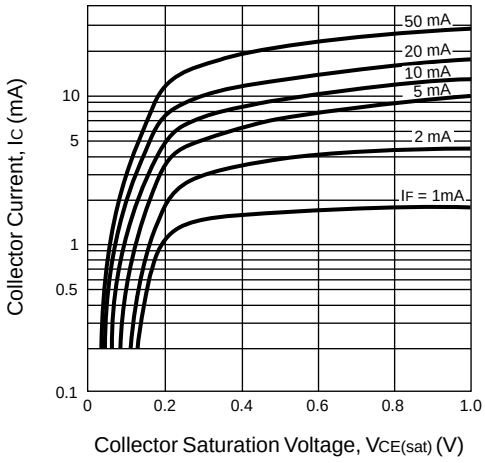


TYPICAL PERFORMANCE CURVES (T_A = 25° C)

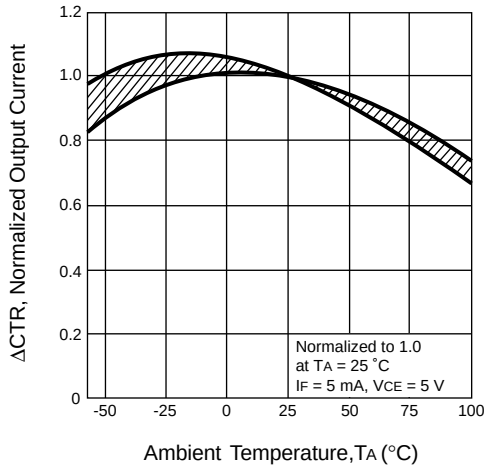
COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE



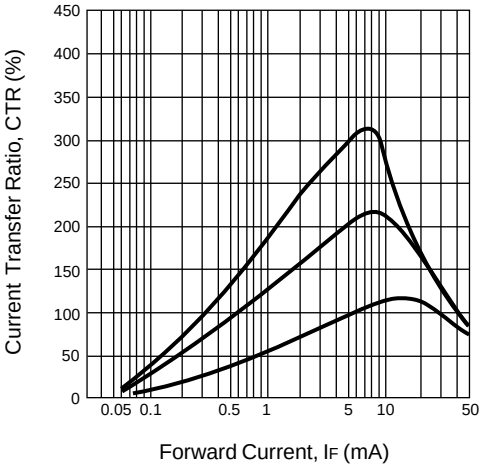
COLLECTOR CURRENT vs. COLLECTOR SATURATION VOLTAGE



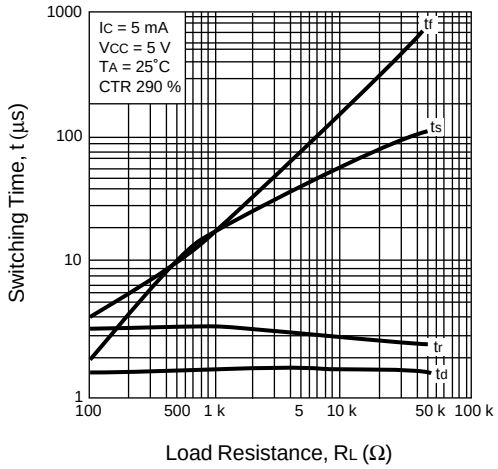
NORMALIZED OUTPUT CURRENT vs. AMBIENT TEMPERATURE



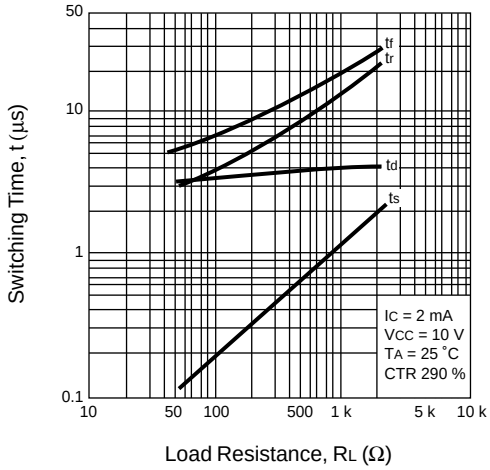
CURRENT TRANSFER RATIO (CTR) vs. FORWARD CURRENT



SWITCHING TIME vs. LOAD RESISTANCE

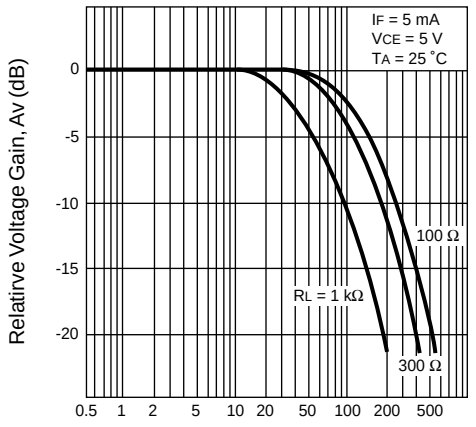


SWITCHING TIME vs. LOAD RESISTANCE

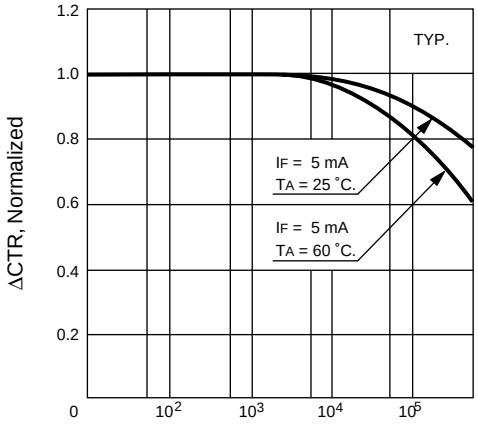


TYPICAL PERFORMANCE CURVES (T_A = 25°)

FREQUENCY RESPONSE

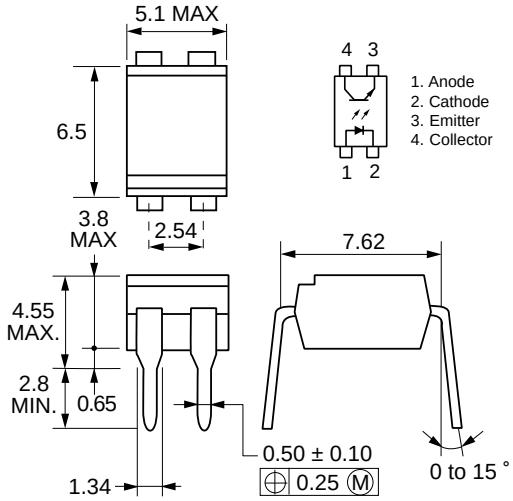


CTR DEGRADATION

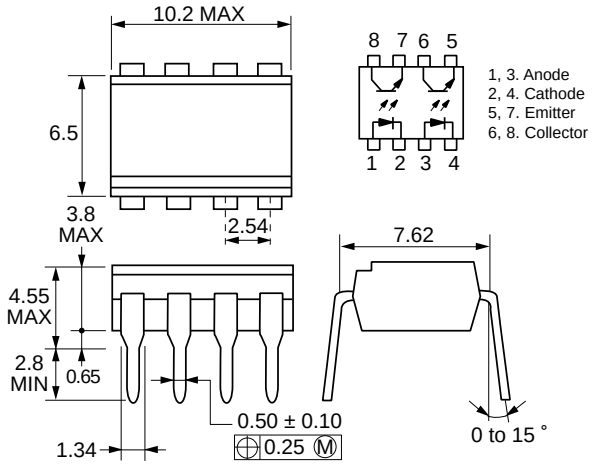


OUTLINE DIMENSIONS (Units in mm) DIP (Dual In-Line Package)

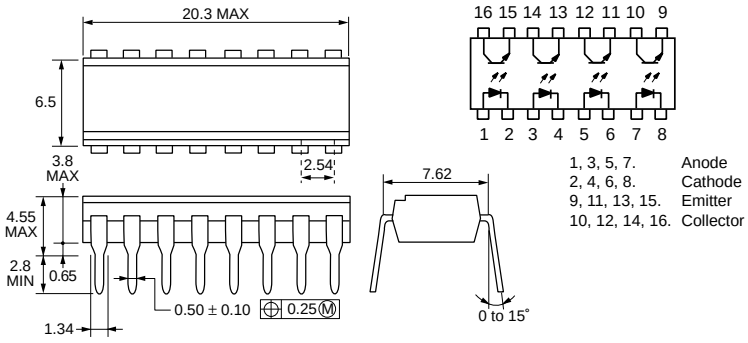
PS2561-1



PS2561-2

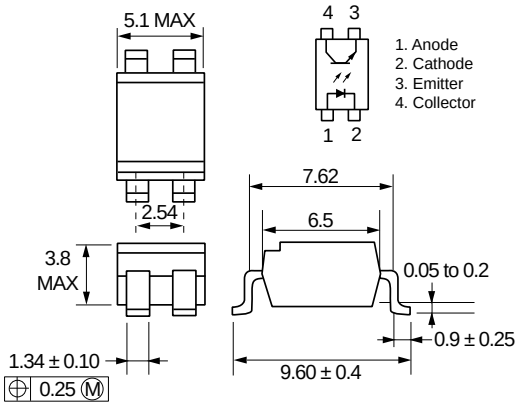


PS2561-4

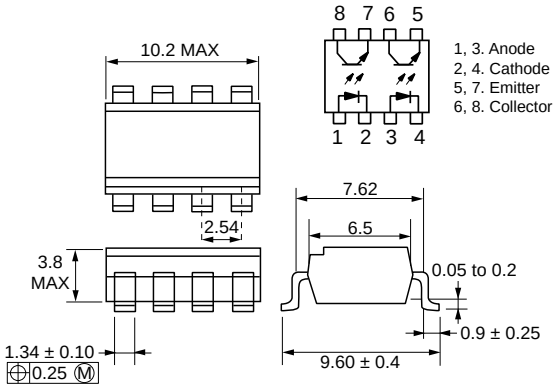


OUTLINE DIMENSIONS (Units in mm) Lead Bending type (Gull-Wing)

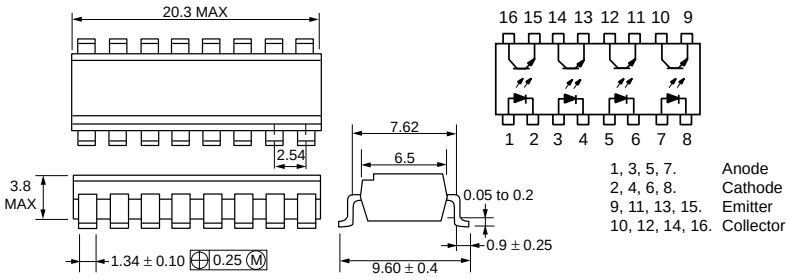
PS2561L-1



PS2561L-2

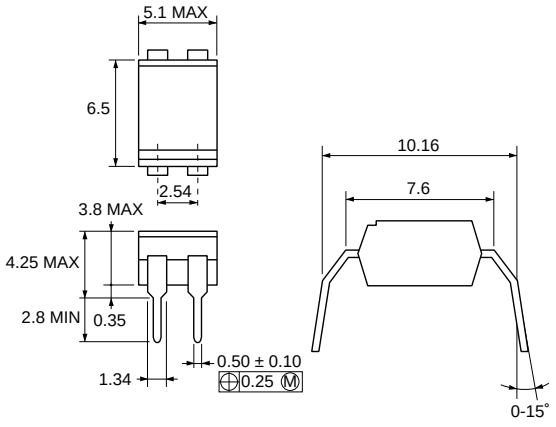


PS2561L-4



OUTLINE DIMENSIONS (Units in mm) DIP (Lead-Bending Type)

PS2561L1-1



PS2561L2-1